Low frequency electromagnetic materials characterization best practice guidance

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Dielectric Permittivity

Polarization *P* describes the dielectric displacement *D* which originates from the response of the material to an external electric field *E*: $\vec{P} = \vec{D} - \varepsilon_0 \vec{E} = (\varepsilon_r^* \varepsilon_0 - \varepsilon_0) \vec{E}$

where:
$$\varepsilon_r^* = \varepsilon_r^{'} - i\varepsilon_r^{''}$$

is complex relative permittivity tensor.

The real part of relative permittivity is the dielectric constant The dielectric loss tangent is calculated as:

$$tg\delta = \frac{\mathcal{E}_r}{\mathcal{E}_r}$$



Measurement methods for dielectric materials measurements

- Impedance measurement using the Four-Terminal Method
- Impedance measurement using Coaxial Line Reflectometry



• The four terminal method is used up to frequencies where sample can be interpreted as a lumped element model



- Dipolar relaxation can be described by an electrical equivalent circuit consisting of capacitance *Cs*² connected in parallel with resistance *Rs*.
- Cs' and Rs can be measured and related to material's dielectric properties \mathcal{E}_{r} and \mathcal{E}_{r} .



- Interconnecting leads and electrodes introduce serial residual inductance Lr and residual resistance Rr
- When measuring *Cs* resonance will occur at frequency f_{LC} :



- At f_{LC} energy is stored in the magnetic field so this resonance is not useful for measurement of dielectric permittivity
- This is most common source of systematic errors in dielectric metrology



- An equivalent complex impedance Zs can be determined from which Cs' and Rs can be calculated and then the material's relative complex permittivity determined
- In the low frequency range wave propagation effects can be neglected
- For a capacitor filled with dielectric material resulting in complex capacitance *Cs*, the permittivity is defined by:

$$\varepsilon_r^*(\omega) = \varepsilon_r^{'}(\omega) - i\varepsilon_r^{''}(\omega) = \frac{\overline{C}s}{C_0}$$

• Here *C*₀ is capacitance of the empty cell without the dielectric present



• The impedance **Z**s of the sample, consistent with equivalent circuit, is defined as:

 C₀ can be determined from specimen geometry or by measurements of reference materials with known dielectric permittivity



- Standard measurement procedures recommend a threeterminal (3T) cell configuration with guard electrode (G)
- Minimizes effects of fringing and stray electric fields



- All cables as short as possible (low Lr)
- If no guard electrode is used then shields are shorted together



Coaxial Line Reflectometry

- Impedance at higher frequencies can be determined from the reflection coefficient measurement using a VNA (Vector Network Analyzer) or coaxial RF impedance analyzers
- Reflection coefficient are measured using microwave techniques with precision transmission lines
- A specimen with impedance Zs terminates a transmission line with characteristic impedance Z₀ which causes mismatch and reflections
- The relation between **Z**s and complex reflection coefficient **F** is given by:

$$\bar{\Gamma} = \frac{Z_s - Z_0}{\bar{Z}_s + Z_0}$$

assuming the reference plane is at the line/ specimen interface



Coaxial Line Reflectometry

- It follows that when the line is terminated with a short ($Z_{short} = 0$) $\Gamma = -1$, for an open termination ($Z_{open} = \infty$) $\Gamma = 1$, and for ideal load when $Zs = Z_0$, $\Gamma = 0$. (NB. In practice, fringing capacitances have to be taken into account for the open termination).
- These three terminations are usually used for calibration with the reference plane at the specimen position.
- Coaxial test fixtures can be open-ended or short-ended
- Open-ended for large thick specimens or liquid materials
- Short-ended for thin films, specimens with dimensions comparable to the centre conductor of the probe





Coaxial Line Reflectometry

- Dielectric materials with known permittivity are used as references for correcting systematic errors in measuring *Γ* because of differences between measurement and calibration configurations
- If the circuit can be described with lumped parameters then \mathcal{E}_r and \mathcal{E}_r can be obtained from the measured $\mathbf{\Gamma}$ by:

$$\varepsilon_{r}^{'} = \frac{-2\left|\bar{\Gamma}\right|\sin\varphi}{\omega Z_{0}C_{0}(1+2\left|\bar{\Gamma}\right|\cos\varphi + \left|\bar{\Gamma}\right|^{2})}$$
$$\tan\delta = \frac{\varepsilon_{r}^{''}}{\varepsilon_{r}^{'}} = \frac{1-\left|\bar{\Gamma}\right|^{2}}{-2\left|\bar{\Gamma}\right|\sin\varphi}$$



 Permittivity, dielectric loss and relaxation frequency are temperature dependent so temperature has to be monitored and should normally be kept constant (isothermal conditions) during the measurements





- Sample dimensions have to be accurately measured to minimize errors when calculating permittivity
- Sample faces which come in contact with the electrodes may have to be metalized, especially for high permittivity specimens (metallization performed *after* measuring dimensions)
- Metallization using silver paste, liquid metals (InGa), adhesive cooper foils...





• Air gaps between the electrodes can introduce significant error especially for high permittivity samples

Typical m		Metal	No Metal	Ref. Value	
permittivi	1200.0 -	43,3	41,3	42,0	
		102,1	59,9	103,1	
	1000.0 -	169,4	54	166	
	800.0 -	299,9	62	307	
		1053	236	1100	
	600.0 -	10288	463	11000	





- Long cables from an instrument to a 4TP measuring cell can cause significant errors at higher frequencies (above 500 kHz), especially if the cables are moved.
- This can be corrected by making open, short and known load calibration at the end of the cables
- The load should be chosen so that it's impedance is similar to the impedance of the sample (reference materials can be used)







Conclusions

- The 4TP configuration is used for very low frequencies (5 Hz) and typically up to 30 MHz (possibly 100 MHz, but not many instruments are available for that)
- Lumped transmission line reflectometry can be used up to approximately 5 GHz depending on the sample size and line configuration
- Significant errors can arise from instrumental resonances, temperature instability, long cables, air gaps...
- All relevant equipment should be characterized before use: calibration of instruments, characterization of the cell, etc.
- Reference materials are to be recommended, especially for checking on systematic measurement errors and providing confidence in measurements.

